



## **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	150	mA
Pc	Collector Power Dissipation	250	mW
ТJ	Junction Temperature	150	°C
Т <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

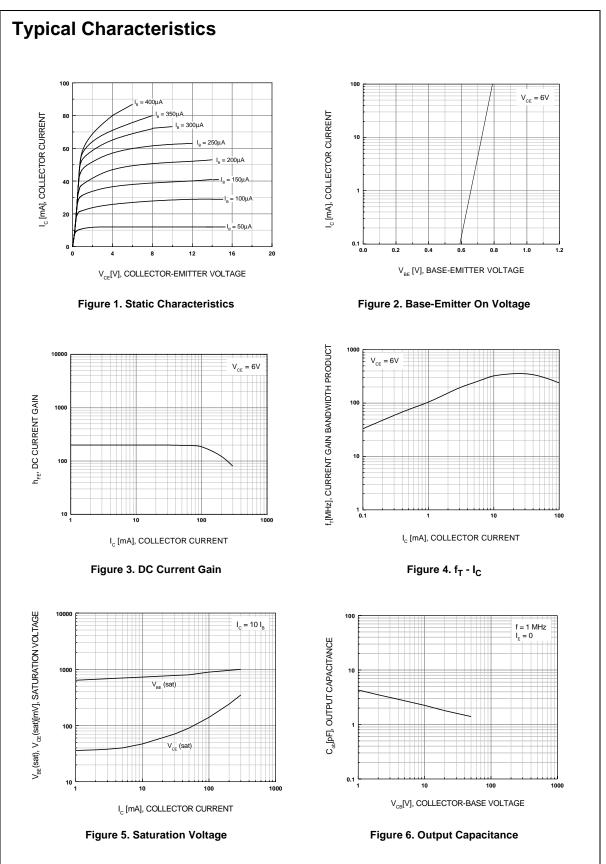
### Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μΑ, I <sub>E</sub> =0	60			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	tor-Emitter Breakdown Voltage I <sub>C</sub> =10mA, I <sub>B</sub> =0				V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =40V, I <sub>E</sub> =0			0.1	μA
IEBO	Emitter Cut-off Current	V <sub>EB</sub> =3V, I <sub>C</sub> =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =6V, I <sub>C</sub> =1.0mA	70		700	- 15
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		0.15	0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =6V, I <sub>C</sub> =10mA		300	LIL.	MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		2.5	. OZ	pF
NF	Noise Figure	V <sub>CE</sub> =6, I <sub>C</sub> =0.5mA f=1KHz, R <sub>S</sub> =500Ω		4.0		dB

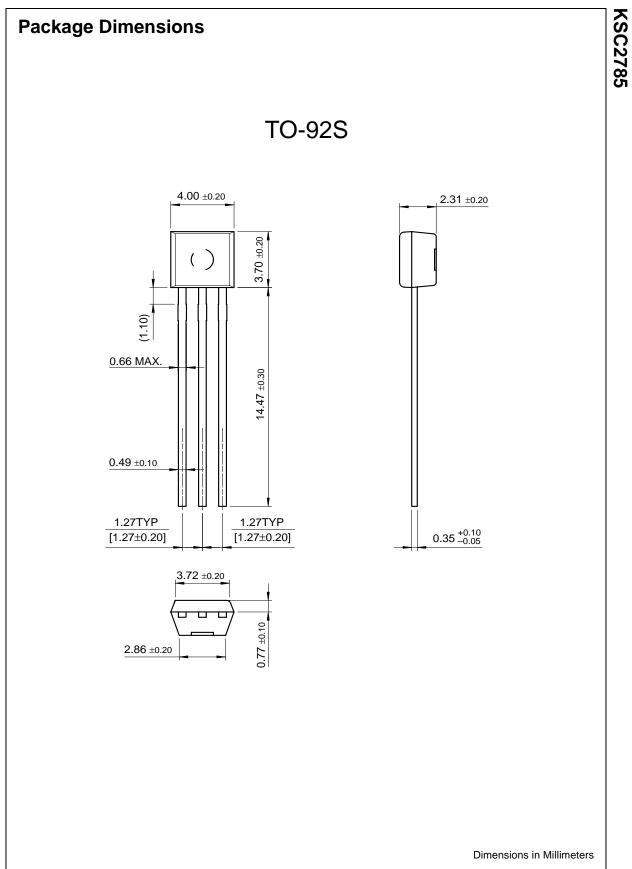
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Classification	0	Y	G	L
h <sub>FE</sub>	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700





# KSC2785



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